

DATASHEET

5 PIN SOP HIGH SPEED 1Mbit/s TRANSISTOR PHOTOCOUPLER ELM45X series

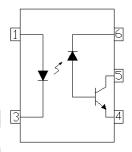


Features

- •Compliance Halogen Free . (Br <900 ppm ,Cl <900 ppm , Br+Cl < 1500 ppm)
- •High speed 1Mbit/s
- High isolation voltage between input and output (Viso=3750 Vrms)
- High CMR 15KV/us at V_{CM}=1500V (ELM453)
- Guaranteed performance from 0°C to 70°C
- Wide operating temperature range of -40°C to 85°C
- Compliance with EU REACH
- Pb free and RoHS compliant
- UL and cUL approved(No. E214129)
- VDE approved (No. 40028116)
- SEMKO approved
- NEMKO approved
- DEMKO approved
- FIMKO approved

Schematic

ELM45X series



Pin Configuration

- 1. Anode
- 3. Cathode
- 4. Gnd
- 5. Vout
- 6. V_{CC}

Description

The ELM452 and ELM453 devices each consist of an infrared emitting diode, optically coupled to a high speed photo detector transistor. A separate connection for the photodiode bias and output-transistor collector increase the speed by several orders of magnitude over conventional phototransistor couplers by reducing the base-collector capacitance of the input transistor. The devices are packaged in industry standard 5pin SOP packages and are suitable for surface mounting.

Applications

- Line receivers
- Field bus communication and control.
- Power transistor isolation in motor drives
- Replacement for low speed phototransistor photo couplers
- · High speed logic ground isolation
- · Analog signal ground isolation

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Absolute Maximum Ratings (Ta=25°C unless otherwise noted)

	Parameter	Symbol	Rating	Unit
	Forward current	I _F	25	mA
	Peak forward current (50% duty, 1ms P.W)	I _{FP}	50	mA
Input	Peak transient current (≤1µs P.W,300pps)	I _{Ftrans}	1	А
	Reverse voltage	V _R	5	V
	Power dissipation	P _{IN}	45	mA mA A V mW mW mA 20 V 30 V rms
	Power dissipation	Po	100	mW
	Average Output current	I _{O(AVG)}	8	mA
Output	Peak Output current	I _{O(PK)}	I _F 25 I _{FP} 50 I _{Ftrans} 1 V _R 5 P _{IN} 45 P _O 100 I _{O(AVG)} 8	mA
	Output voltage	Vo		V
	Supply voltage	V _{CC}	-0.5 to 30	V
Isolation	voltage *1	V _{ISO}	3750	V rms
Operatin	g temperature	T _{OPR}	-40 ~ +85	°C
Storage	temperature	T _{STG}	-55 ~ +125	°C
Soldering	g temperature *2	T _{SOL}	260	°C

Notes:

^{*1} AC for 1 minute, R.H.= 40 ~ 60% R.H. In this test, pins 1 & 3 are shorted together, and pins 4, 5 & 6 are shorted together.

^{*2} For 10 seconds.



Electrical Characteristics (T_A=0 to 70°C unless specified otherwise)

Input

Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition
Forward Voltage	V_{F}	-	1.45	1.8	V	I _F = 16mA
Reverse Voltage	V_R	5.0	-	-	V	I _R = 10μA
Temperature coefficient of forward voltage	$\Delta V_F / \Delta T_A$	-	-1.6	-	mV/°C	I _F =16mA

Output

Parameter	Symbol	Min	Тур.	Max.	Unit	Condition
Logic High Output		-	0.001	0.5	- μΑ	I _F =0mA, V _O =V _{CC} =5.5V, T _A =25°C
Current	I _{OH} -	-	0.001	1		I_F =0mA, V_O = V_{CC} =15V, T_A =25°C
	_	50	<u>-</u>	I _F =0mA, V _O =V _{CC} =15V		
Logic Low Supply Current	I _{CCL}	-	100	200	μΑ	I_F =16mA, V_O =Open, V_{CC} =15V
Logic High Supply	la a	<u>-</u>	0.05	1	- μA	I_F =0mA, V_O =0pen, V_{CC} =15V, T_A =25°C
Current	I _{CCH} -	-		2	μΑ	I_F =0mA, V_O =Open, V_{CC} =15V

Transfer Characteristics

Parameter	Symbol	Min	Тур.	Max.	Unit	Condition
Current Transfer Ratio	CTR -	20	-	50	%	$I_F = 16\text{mA}$, $V_O = 0.4\text{V}$, $V_{CC} = 4.5\text{V}$, $T_A = 25^{\circ}\text{C}$
Current Hansler Ratio	CIK	15	-	-		$I_F = 16mA$, $V_O = 0.5V$, $V_{CC} = 4.5V$
Logic Low Output	V	-	-	0.4	V	$I_F = 16mA$, $I_O = 3mA$, $V_{CC}=4.5V$, $T_A=25$ °C
Voltage	V _{OL} -	-	-	0.5	V	I _F = 16mA ,I _O = 2.4mA, V _{CC} =4.5V



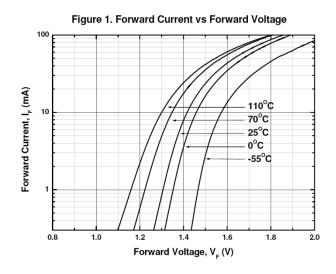
Switching Characteristics (T_A=0 to 70°C unless specified otherwise, Vcc=5V)

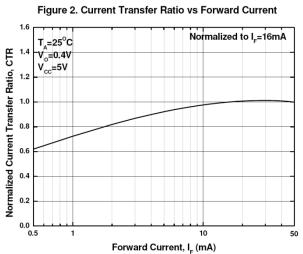
Parameter		Symbol	Min	Тур.	Max.	Unit	Condition
Propagation Delay Time		T _{PHL}	_	0.4	0.8	μs	IF=16mA, R _L =1.9KΩ, T_A =25°C
to Logic Lov	v ⁽³ /(Fig.8)	· FIIL	-	-	1.0	-	IF=16mA, R_L =1.9KΩ
	Propagation Delay Time to Logic High		_	0.35	0.8	μs	IF=16mA, R _L =1.9KΩ, T_A =25°C
^(*3) (Fig.8)	, 3	T_PLH	-	-	1.0	-	IF=16mA, R_L =1.9KΩ
Common Mode Transient	ELM452	СМн	5,000	-	-		$I_F = 0$ mA, $V_{CM} = 10$ Vp-p, $R_L = 1.9$ K Ω , $T_A = 25$ °C
immunity at Logic High ^(*4) (Fig.9)	High ^(₹4) ELM453		15,000	-	-	V/µs	I_F = 0mA , V_{CM} =1500Vp-p, R_L =1.9K Ω , T_A =25°C
Common Mode Transient	Common Mode ELM452 Transient		5,000	-	-		$I_F = 16\text{mA}$, $V_{CM} = 10\text{Vp-p}$, $R_L = 1.9\text{K}\Omega$, $T_A = 25^{\circ}\text{C}$
Immunity at Logic Low ELM453 (Fig.9)*3		CM _L	15,000	-	-	V/µs	$I_F = 16\text{mA} ,$ $V_{\text{CM}} = 1500 \text{Vp-p} ,$ $R_L = 1.9 \text{K}\Omega, T_A = 25^{\circ}\text{C}$

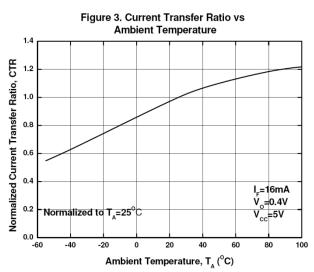
^{*} Typical values at T_a = 25°C

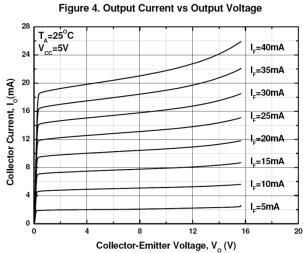


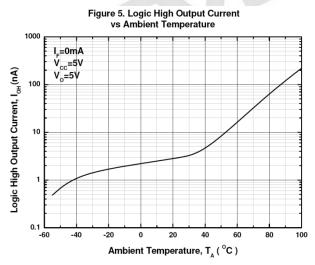
Typical Electro-Optical Characteristics Curves

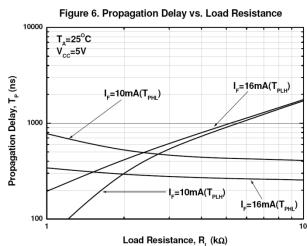


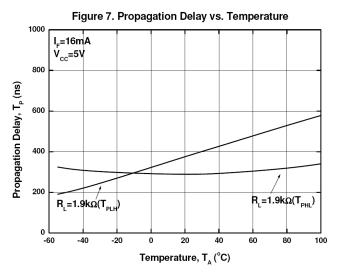












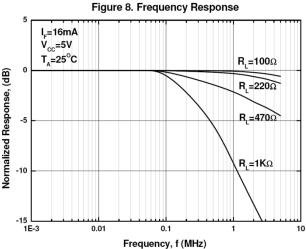
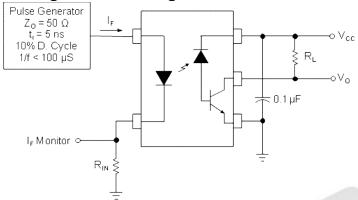


Figure 9 Switching Time Test Circuit & Waveform



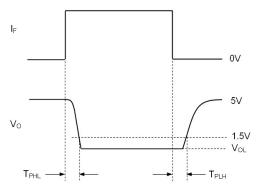
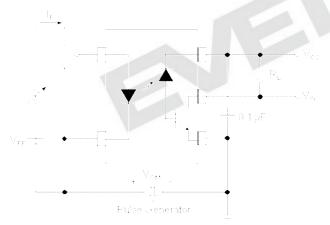
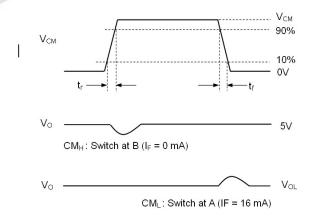


Figure 10 Transient Immunity Test Circuit & Waveform





Note:

*3 Common mode transient immunity in logic high level is the maximum tolerable (positive) dVcm/dt on the leading edge of the common mode pulse signal VCM, to assure that the output will remain in a logic high state (i.e., VO > 2.0V).

Common mode transient immunity in logic low level is the maximum tolerable (negative) dVcm/dt on the trailing edge of the common mode pulse signal, VCM, to assure that the output will remain in a logic low state (i.e., VO < 0.8V).



Order Information

Part Number

ELM45X(Z)-V

Note

X = Part No. (2 or 3)

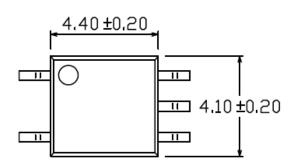
Z = Tape and reel option (TA, TB or none)

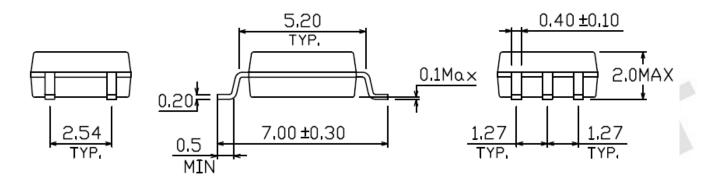
V = VDE (optional)

Option	Description	Packing quantity
None	Standard	100 units per tube
-V	Standard + VDE	100 units per tube
(TA)	TA tape & reel option	3000 units per reel
(TB)	TB tape & reel option	3000 units per reel
(TA)-V	TA tape & reel option + VDE	3000 units per reel
(TB)-V	TB tape & reel option + VDE	3000 units per reel

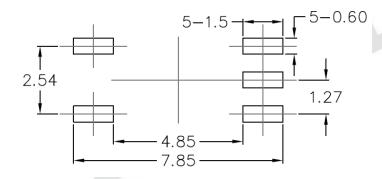


Package Dimension (Dimensions in mm)





Recommended pad layout for surface mount leadform





Device Marking

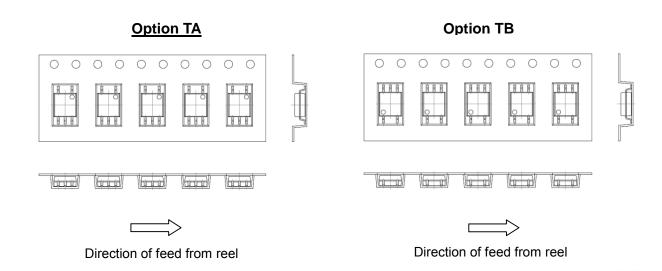


Notes

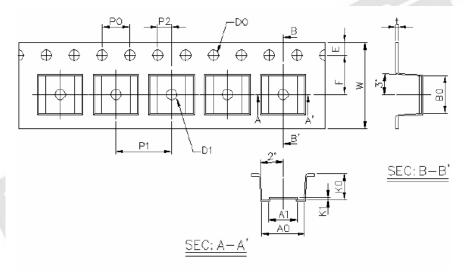
EL denotes EVERLIGHT
M453 denotes Device Number
Y denotes 1 digit Year code
WW denotes 2 digit Week code
V denotes VDE (optional)



Tape & Reel Packing Specifications



Tape dimensions



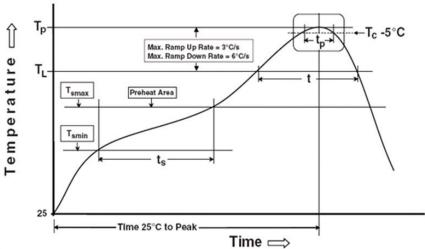
Dimension No.	Α0	A1	В0	D0	D1	E	F
Dimension(mm)	6.2±0.1	4.1±0.1	5.28±0.1	1.5±0.1	1.5±0.3	1.75±0.1	5.5±0.1
Dimension No.	Ро	P1	P2	t	W	K0	K1
Dimension(mm)	4.0±0.1	8.0±0.1	2.0±0.1	0.4±0.1	12.0+0.3/ -0.1	3.7±0.1	0.3±0.1



Precautions for Use

1. Soldering Condition

1.1 (A) Maximum Body Case Temperature Profile for evaluation of Reflow Profile



Note:

Preheat

Temperature min (T_{smin})

Temperature max (T_{smax})

Time $(T_{smin} \text{ to } T_{smax}) (t_s)$

Average ramp-up rate $(T_{smax} to T_p)$

Other

Liquidus Temperature (T_L)

Time above Liquidus Temperature (t₁)

Peak Temperature (T_P)

Time within 5 °C of Actual Peak Temperature: T_P - 5°C

Ramp- Down Rate from Peak Temperature

Time 25°C to peak temperature

Reflow times

Reference: IPC/JEDEC J-STD-020D

150 °C

200°C

60-120 seconds

3 °C/second max

217 °C

60-100 sec

260°C

30 s

6°C /second max.

8 minutes max.

3 times



DISCLAIMER

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